

Pressure Sensor series

Pressure Sensor IC

BM1386GLV

General Description

BM1386GLV is piezo-resistive pressure sensor. BM1386GLV performs temperature compensation for MEMS inside chip internally, so it's very easy to get pressure information.

Features

- Piezo-resistive pressure sensor
- Pressure range is from 300hPa to 1300hPa
- Built-in temperature compensation function
- I2C bus interface (f/s mode support)
- Built-in FIFO
- Small package

Applications

■ Smartphone, Healthcare, mobile device (e.g. game).

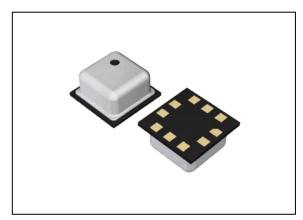
Key Specifications

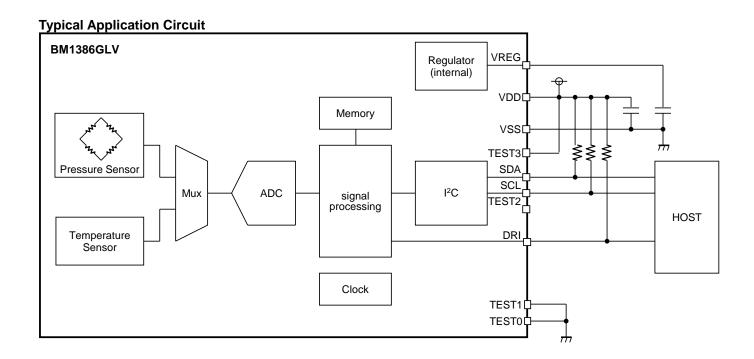
Pressure Range: 300hPa to 1300hPa
 Relative Pressure Accuracy: ±0.12hPa(Typ)
 Absolute Pressure Accuracy: ±1hPa(Typ)
 Operating Temperature Range: -40°C to +85°C

Package

CLGA10V020A

W(Typ) x D(Typ) x H(Max) 2.0mm x 2.0mm x 1.0mm





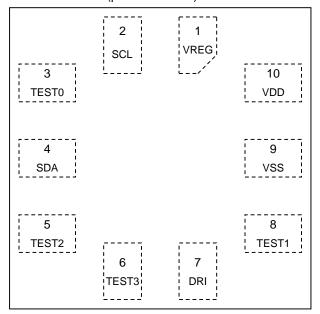
OProduct structure: Silicon monolithic integrated circuit OThis product has no designed protection against radioactive rays

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Pin Configuration

Top View (pads not visible)

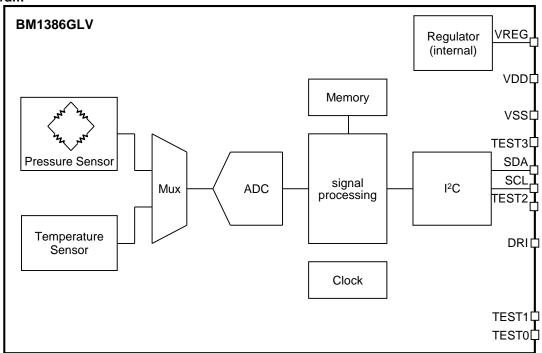


Pin Description

2 00011ptiol		
Pin No.	Pin Name	Function
1	VREG	Internal power supply pin ^(Note 1)
2	SCL	I2C serial bus colck pin
3	TEST0	Test pin (connect to VSS)
4	SDA	I2C serial bus data pin
5	TEST2	Test pin (open)
6	TEST3	Test pin (connect to VDD)
7	DRI	Interrupt notice output pin
8	TEST1	Test pin (connect to VSS)
9	VSS	Ground pin
10	VDD	power voltage pin ^(Note 2)

(Note 1) Dispose a bypass capacitor as close as possible to the IC.
Please set a bypass capacitor of 0.22µF between DREG and VSS.
Please do not use this pin for external power source.
(Note 2) Dispose a bypass capacitor as close as possible to the IC.

Block Diagram



Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Rating	Unit
Power Supply	V_{DD_MR}	4.5	V
Input Voltage1 ^(Note 1)	V _{IN1MR}	-0.3 to +4.5	٧
Input Voltage2 ^(Note 2)	V _{IN2MR}	-0.3 to (VDD+0.3) or +4.5 whichever is less	V
Storage Temperature	Tstg	-40 to +125	°C
Maximum Junction Temperature	Tjmax	125	°C
Pressure	Povr	20000	hPa

(Note 1) DRI, SCL, SDA pin (Note 2) except DRI, SCL, SDA pin

Caution 1: Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins and the internal circuitry. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is

operated over the absolute maximum ratings.

Caution 2: Should by any chance the maximum junction temperature rating be exceeded the rise in temperature of the chip may result in deterioration of the properties of the chip. In case of exceeding this absolute maximum rating, increase the board size and copper area to prevent exceeding the maximum junction temperature rating.

Thermal Resistance^(Note 1)

Darameter	Cumbal	Thermal Res	Lloit		
Parameter	Symbol	1s ^(Note 3)	2s2p ^(Note 4)	Unit	
CLGA10V020A					
Junction to Ambient	θ_{JA}	339.7	217.5	°C/W	
Junction to Top Characterization Parameter ^(Note 2)	Ψ_{JT}	154	140	°C/W	

(Note 1)Based on JESD51-2A(Still-Air)

(Note 2)The thermal characterization parameter to report the difference between junction temperature and the temperature at the top center of the outside surface of the component package.

3)Using a PCB board based on JESD51-3

[Note 5/03ing a 1 CB board based on 3E0B31-3.							
Layer Number of Measurement Board	Material	Board Size					
Single	FR-4	114.3mm x 76.2mm x 1.57mmt					
Тор							
Copper Pattern	Thickness						
Footprints and Traces	70µm						

(Note 4)Using a PCB board based on JESD51-7.

Layer Number of Measurement Board	Material	Board Size
4 Layers	FR-4	114.3mm x 76.2mm x 1.6mmt

Тор		2 Internal Laye	ers	Bottom		
Copper Pattern	Thickness	Copper Pattern	Thickness	Copper Pattern	Thickness	
Footprints and Traces	70µm	74.2mm x 74.2mm	35µm	74.2mm x 74.2mm	70µm	

Recommended Operating Conditions

Parameter	Symbol	Min	Тур	Max	Unit
Power Supply	V _{DD}	1.7	1.8	3.6	V
Input Voltage1 ^(Note 1)	V _{IN1}	0.0	-	3.6	V
I ² C clock Input Frequency	fscL	-	-	400	kHz
Operating Temperature	Topr	-40	+25	+85	°C

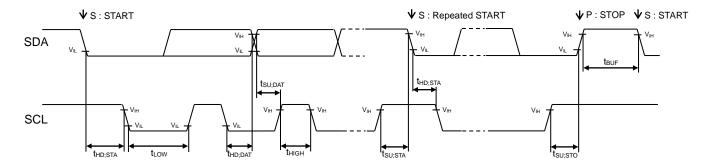
(Note 1) DRI, SCL, SDA pin

Electrical Characteristics (Unless otherwise specified VDD=1.8V Ta=25°C)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Current Consumption			I	I	I	
Power Down Mode Current	Iss	-	1	5	μΑ	PWR_DOWN=0, RSTB=0
Logic						
L Input Voltage ^(Note 1)	VIL	-	-	0.3 * VDD	V	
H Input Voltage ^(Note 1)	ViH	0.7 * VDD	-	-	V	
L Input Current ^(Note 1)	I _{IL}	-10	-	-	μΑ	VIL = GND
H Input Current ^(Note 1)	Iн	-	-	10	μΑ	VIH = VDD
L Output Voltage 1 ^(Note 2)	V _{OL1}	-	-	0.2 * VDD	V	IL = -0.3mA
L Output Voltage 2 ^(Note 3)	V _{OL2}	-	-	0.2 * VDD	V	IL = -3mA
Pressure characteristics						
Pressure Detection Range	P _R	300	-	1300	hPa	0°C to 65°C
Relative Pressure Accuracy ^(Note 4)	Prel	-	±0.12	-	hPa	950hPa to 1050hPa
Absolute Pressure Accuracy	Pabs	-	±1	-	hPa	1000hPa
Temperature Accuracy	Tabs	-	±2	-	°C	25°C to 85°C
Measurement Time ^(Note 5)	Tm	-	-	6	msec	AVE_NUM=000

(Note 1) SDA, SCL pin
(Note 2) DRI pin
(Note 3) SDA pin
(Note 4) Target values
(Note 5) Measurement time is changed by average number of measurement data. It is written in Measurement time more detail.

I²C Bus Timing Characteristics (Unless otherwise specified VDD=1.8V, Ta=25°C)



Parameter	Symbol	Min	Тур	Max	Unit	Conditions
SCL Clock frequency	fscL	0	-	400	kHz	
'L' Period of the SCL Clock	tLOW	1.3	-	-	μs	
'H' Period of the SCL Clock	tніgн	0.6	-	-	μs	
Setup Time for Repeated START	tsu;sta	0.6	-	-	μs	
Hold Time for START	thd;sta	0.6	-	-	μs	
Data Setup Time	t _{SU;DAT}	100	-	-	ns	
Data Hold Time	thd;dat	0	-	-	μs	
Setup Time for STOP	t _{SU;STO}	0.6	-	-	μs	
Bus Free Time between STOP and START	t _{BUF}	1.3	-	-	μs	

I²C Bus Communication

- 1. Write Format
 - (1) Indicate register address

S	Slave Address	W 0	ACK	Register Address	ACK	Р	
---	---------------	--------	-----	------------------	-----	---	--

(2) Write data after indicating register address

S	Slave Address	W 0	ACK	F	Register Address	ACK		
ſ	Data specified at register address field	ACK		ACK	Data specified at readdress field +	0	ACK	Р

- 2. Read Format
 - (1) Read data after indicating register address

S	Slave Address	W 0	ACK	Register Address		ACK		
S	Slave Address	R 1	ACK	Data specified at register address field		ACK		
	Data specified at register address field + 1	ACK		ACK	Data specified at re address field +		NACK	Р

(2) Read data from the specified register

S	Slave Address		R 1	ACK	Data specified at register address field		ACK		
	Data specified at register address field + 1	AC	K		ACK Data specified at regist address field + N		•	NACK	Р
					,				

	from master to slave		from slave to master
--	----------------------	--	----------------------

I²C bus Slave Address

The slave address is "1011101".

Register Map^(Note 1)

Register Address	Register Name	R/W	D7	D6	D5	D4	D3	D2	D1	D0
0x0F	MANUFACTURER ID	R			M	IANUFACT	URER ID [7	7:0]		
0x10	PART ID	R				PART	ID [7:0]			
0x12	POWER_DOWN	RW	0	0	0	0	0	0	0	PWR_ DOWN
0x13	RESET	RW	0	0	0	0	0	0	0	RSTB
0x14	MODE_CONTROL	RW	А	VE_NUM[2	2:0]	DR_EN	FULL _EN	WTM _EN	MOD	E[1:0]
0x15	IIR, FIFO CONTROL	RW	FIFO_ EN	WTM_ LEVEL	0	0	0	0	IIR_MO	DE[1:0]
0x18	FIFO data	R	0	0			FIFO_L	.EV[5:0]		
0x19	STATUS	R	0	0	0	0	0	RD_ FULL	RD_ WTM	RD_ DRDY
0x1A		R				PRESS_	OUT[15:8]			
0x1B	PRESSURE	R				PRESS_	OUT[7:0]			
0x1C		R			PRESS_C	OUT_XL[5:0)]		0	0
0x1D	TEMPEDATURE	R				TEMP_C	OUT[15:8]			
0x1E	TEMPERATURE	R				TEMP_	OUT[7:0]			

(Note 1)Do not write any commands to other addresses except above. Do not write '1' to the fields in which value is '0' in above table.

Address from 0x14 to 0x1E registers can be accessed only when PWR_DOWN=1 and RSTB=1. (In other case Write: Ignored, Read: 0xXX)

(0x0F) MANUFACTURER ID

(0,101) 1111 11 101 710 1011211 12	
Fields	Function
MANUFACTURER ID [7:0]	Manufacturer ID : 0xE0

(0x10) PART ID

Fields	Function
PART ID [7:0]	Part ID: 0x33

(0x12) POWER_DOWN

Fields	Function					
PWR_DOWN	0: power down 1: active					

default value 0x00

(0x13) RESET

Fields Function	
RSTB	Measurement control block is reset Measurement control block is active

default value 0x00

(0x14) MODE CONTROL

Fields	Function
AVE_NUM[2:0]	Seting of the averaging number of measurement data 000: single, 001: 2 times, 010: 4 times, 011: 8 times, 100: 16 times, 101: 32 times, 110: 64 times, 111: Prohibited
DR_EN	DRI pin Enable for Data Ready Details are written in Interrupt. 0 : DRI pin Disable, 1 : DRI pin Enable
FULL_EN	DRI pin Enable for FULL Details are written in Interrupt. 0 : DRI pin Disable, 1 : DRI pin Enable
WTM_EN	DRI pin Enable for Water Mark Details are written in Interrupt. 0 : DRI pin Disable, 1 : DRI pin Enable
MODE[1:0]	Measurement mode setting (Pressure and Temperature are measured at one rate) 00 : Stand by, 01 : One shot, 10 : Continuous, 11 : Prohibited

default value 0x00

Measurement time and RMS noise against number of average

ıv	measurement time and ravio holde against number of average						
	AVE_NUM	Measurement time T _m max[ms]	Measurement cycle T _i max[ms]	RMS noise [hPa]			
	000	6	60	0.090			
	001	9	60	0.063			
	010	16	60	0.045			
	011	30	60	0.032			
	100	60	60	0.023			
	101	120	120	0.016			
Ī	110	240	240	0.011			

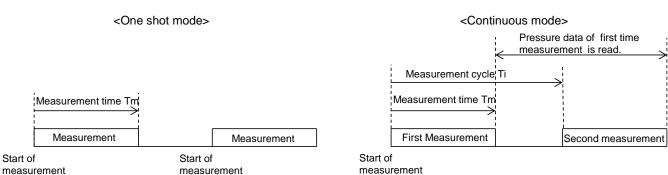
RMS noise is calculated as standard deviation of 32 data points (1 σ). RMS noise is a reference value and it's not the value with guarantee. Condition VDD=1.8V, Ta=25°C, IIR_MODE=00

Measurement time

One shot mode perform one measurement. Measurement data is updated when measurement completed, so it should be read more than T_m after measurement start.

Continuous mode repeat measurement in every measurement cycle T_i . The latest measurement data which is completed is read.

Measurement time T_{m} and measurement cycle T_{i} is determined by number of average.



Operation mode transition

Please refer to the below figure of operation mode transition.

Power down mode is the smallest current consumption mode due to circuit is OFF. Please set this mode when reducing current consumption. Measurement is not available in this mode, so the measurement is performed after switching to standby mode.

In reset mode, regulator for internal blocks is active and measurement control block is reset. Register is initialized in Reset mode. Measurement command is acceptable when "1" is written in "RSTB"

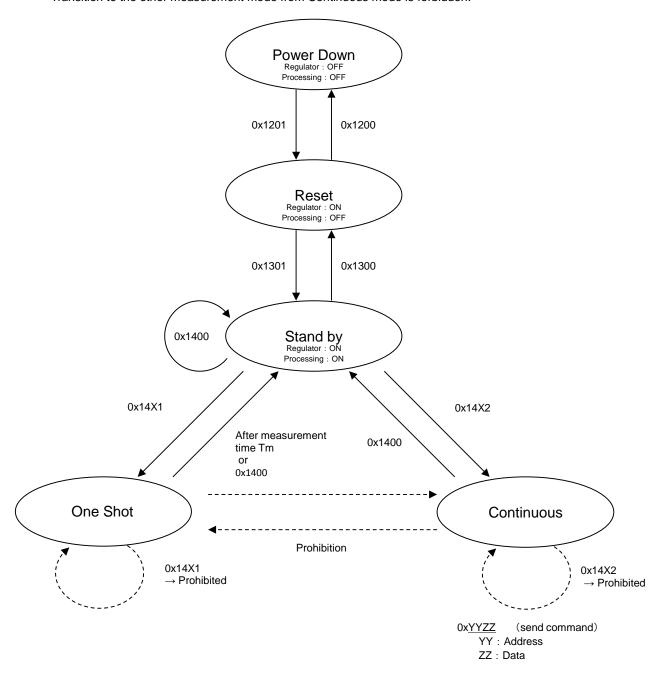
There are 2 measurement modes. One shot mode and Continuous mode. They are transferred from stand by mode. Then, please set "AVE_NUM" register at the same time.

Please write "0x1400" when transferring to standby mode again.

In one shot mode, a single measurement is performed when "01" is written in "MODE". After the measurement completes, it is transferred to standby mode automatically. When "0x1400" is written before end of measurement, mode is switched to standby immediately but pressure value is not updated.

Transition to the other measurement mode during measurement in one shot mode is forbidden.

In Continuous mode, when "10" is written in "MODE", measurement starts and it continues until "0x1400" is written. Transition to the other measurement mode from Continuous mode is forbidden.



(0x15) IIR. FIFO CONTROL

Fields	Function	Function			
FIFO_EN	FIFO mode setting Details are written in FIFO. 0: Bypass mode, 1: FIFO mode				
WTM_LEVEL	Water Mark level setting Details are written in FIFO. 0: Water Mark interrupt occur when FIFO memory is 24 or above. 1: Water Mark interrupt occur when FIFO memory is 28 or above.				
IIR_MODE[1:0]	IIR filter enable and coefficient setting 00 : IIR OFF, 01 : IIR ON (weak) 10 : IIR ON (middle), 11 : IIR ON (strong)				

default value 0x00

(0x18) FIFO data

Fields	Function
FIFO_LEV[5:0]	Number of sample in FIFO

default value 0x00

FIFO LEV[5:0]

<u> </u>	1 [0.0					
D5	D4	D3	D2	D1	D0	Description
0	0	0	0	0	0	FIFO empty
0	0	0	0	0	1	Number of sample in FIFO =1
:	:	:	:	:	:	
1	0	0	0	0	0	FIFO FULL

(0x19) STATUS

Fields	Function				
RD_FULL	FIFO overrun (FULL) status This register is cleared when this is read. RD_FULL is not updated unless data are read. 0: FIFO is not full; 1: FIFO is full.				
RD_WTM	FIFO threshold (Water Mark) status This register is cleared when FIFO memory become less than threshold level. 0: Number of sample in FIFO is lower than threshold level. 1: Number of sample in FIFO is equal or higher than threshold level.				
RD_DRDY	Pressure and temperature measurement data ready bit This register is cleared when '1' is read. Do not care RD_DRDY in FIFO mode (FIFO_EN=1). 0: data is not updated 1: data is updated				

default value 0x00

(0x1A/0x1B/0x1C) PRESSURE

Fields	Function
PRESS_OUT[15:0] PRESS_OUT_XL[5:0]	pressure data

default value 0x000000

Conversion to pressure value is below.

Pressure counts = PRESS_OUT[15:8] x 2^{14} + PRESS_OUT[7:0] x 2^{6} + PRESS_OUT_XL[5:0] [counts] (dec) Pressure value [hPa] = Pressure counts [counts] / 2048 [counts/hPa]

Data registers (0x1A, 0x1B, 0x1C) should be read by burst read.

Data is updated at the timing of measurement completion.

If they are not read by burst read, data might be mixed up with the data of different measurement.

(0x1D/0x1E) TEMPERATURE

Fields	Function
TEMP_OUT[15:0]	temperature data

default value 0x0000

Conversion to temperature value is below. Please note that TEMP_OUT is data with sign (two's complement).

Temp counts = TEMP_OUT[15:8] x 2⁸ +TEMP_OUT[7:0] [counts] (dec)
Temperature value [°C] = Temp counts [counts] / 32 [counts/°C]
(in case of positive number)

Data registers (0x1D,0x1E) should be read by burst read.

Data is updated at the timing of measurement completion.

If they are not read by burst read, data might be mixed up with the data of different measurement.

FIFO

This IC embeds a 32-slot FIFO to store the pressure and temperature output values.

FIFO has Bypass mode (FIFO_EN=0) and FIFO mode (FIFO_EN=1).

In FIFO mode, the pressure and temperature output values are stored in FIFO when measurement is completed.

The data is read from oldest data.

Interrupt for WTM and FULL is available in FIFO mode.

WTM interrupt is enable when WTM_EN is set to '1'. In this mode, when FIFO memory reach the number set in WTM_LEVEL, RD_WTM goes to '1'.

FULL interrupt is enable when FULL_EN is set to '1'. In this mode, when 32 data are stored in FIFO, RD_FULL goes to '1'.

FIFO_LEV is the number of sample in FIFO.

FIFO is only available in Continuous mode.

<Bypass mode>

FIFO is not operational in Bypass mode (FIFO_EN=0).

New data is overwritten to old data due to only the first slot of FIFO is in use.

FIFO and FIFO_LEV are initialized in Bypass mode.

	FI		
\Longrightarrow	Pressure data 0	Temerature data 0	
ŗ	Pressure data 1	Temerature data 1	,
	Pressure data 2	Temerature data 2	
	:	:	
	Pressure data 23	Temerature data 23	
	Pressure data 24	Temerature data 24	
	:	:	
	Pressure data 31	Temerature data 31	

<FIFO mode>

FIFO is operational in FIFO mode (FIFO_EN=1). Pressure data is read from the address 0x1A, 0x1B and 0x1C and temperature data is read from the address 0x1D and 0x1E.

The data is read from oldest data. FIFO stops storing data when FIFO is FULL.

	FIFO					
\Longrightarrow	Pressure data 0	Temerature data 0				
r	Pressure data 1	Temerature data 1				
	Pressure data 2	Temerature data 2				
	:	:				
	Pressure data 23	Temerature data 23				
	Pressure data 24	Temerature data 24				
	:	:				
	Pressure data 31	Temerature data 31				

Water Mark interrupt

Water Mark interrupt occur when stored data in FIFO is equal to or more than the number set in WTM_LEVEL.

Water Mark level is selectable from 24 (WTM_LEVEL=0) and 28 (WTM_LEVEL=1).

RD_WTM goes to '1' when Water Mark interrupt occur

Water Mark interrupt keep active state while FIFO_LEV is equal to or more than WTM_LEVEL. And it is released, when FIFO_LEV go below WTM_LEVEL.

DRI pin status is determined by Water Mark interrupt, when WTM_EN is '1'.

	Case of Water Mark occ	level	
	FII		
\Longrightarrow	Pressure data 0	Temerature data 0	
·	Pressure data 1	Temerature data 1	
	Pressure data 2	Temerature data 2	
	÷	:	
	Pressure data 23	Temerature data 23	
	Pressure data 24	Temerature data 24	
	÷	:	
	Pressure data 31	Temerature data 31	

FULL interrupt

FULL interrupt occur when stored data in FIFO is 32. RD_FULL goes '1'.

RD_FULL goes '0' when RD_FULL is read.

FIFO and RD_FULL are not updated by measurement after FULL interrupt occur. Then FIFO_LEV is fixed to 32.

DRI pin status is determined by FULL interrupt, when FULL_EN is '1'.

	Case of FULL occurs		_				
	FIFO						
\Longrightarrow	Pressure data 0	Temerature data 0					
·	Pressure data 1	Temerature data 1					
	Pressure data 2	Temerature data 2					
	:	:					
	Pressure data 23	Temerature data 23					
	Pressure data 24	Temerature data 24					
	:	:					
	Pressure data 31	Temerature data 31					

Interrupt function

Interrupt factor is Data Ready, FIFO FULL and FIFO WTM.

The condition is listed below.

The status register is always operational.

The status register goes '1' when interrupt occur.

When the DRI pin enable register for each factor is '1', DRI pin status is determined by the interrupt state of factor. When interrupt occur, DRI pin output 'L'.

The status register and DRI pin keeps the state until the interrupt is cleared.

FIFO FULL and FIFO WTM are not available in Bypass mode (FIFO_EN=0)

Do not care Data Ready in FIFO mode (FIFO_EN=1).

Interrupt factor

Factor	Status register	Interrupt condition	Interrupt Clear condition
Data Ready	RD_DRDY	Measurement completion	Read RD_RDRY
FIFO FULL	RD_FULL	FIFO is Full	Read RD_FULL
FIFO WTM	RD_WTM	FIFO_LEV≧WTM level	FIFO_LEV <wtm level<="" td=""></wtm>

Relation between factor and DRI pin enable

Factor	DRI pin enable				
Data Ready	DR_EN				
FIFO FULL	FULL_EN				
FIFO WTM	WTM EN				

DRI pin is Nch open drain so this terminal should be pull-up to voltage source by an external resister.

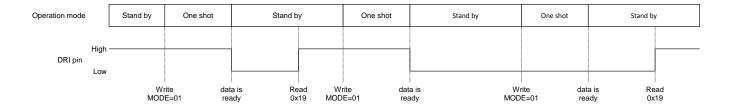
DRI pin is high impedance just after VDD is supplied.

DRI pin becomes inactive (High impedance) by reading RD_DRDY register or setting reset mode.

VDD current (approximately 6µA at VDD=1.8V) is consumed during DRI is active.

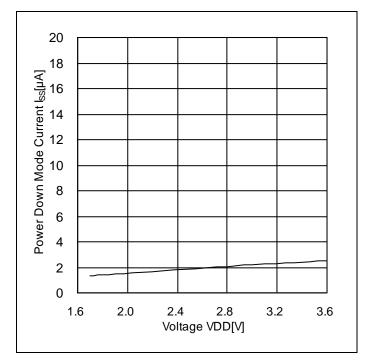
When disabling interrupt function, please disable after clearing interrupt.

<Example of Data Ready interrupt : 1shot mode>



Typical Performance Curves

(Reference data) (Unless otherwise specified VDD=1.8V Ta=25°C)



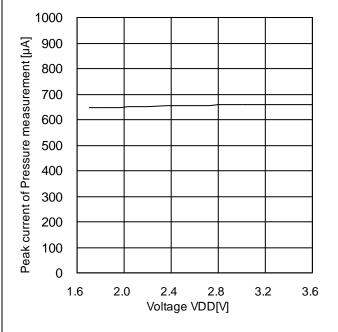
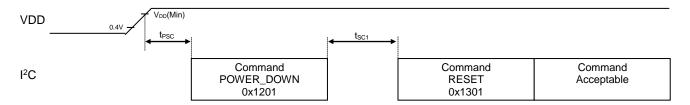


Figure 1. Current vs VDD (PWR_DOWN=0, RSTB=0)

Figure 2. Current vs VDD (During measurement)

Control sequence

1. Power-on sequence

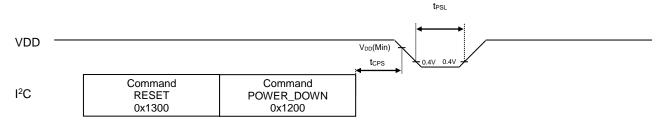


Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Command input time after power-on	tpsc	100	-	-	μs	
Reset cancel wait time	tsc1	1	-	-	ms	VREG:0.22µF

t_{PSC} after VDD power-on, command can be input.

Please send reset cancel command (RSTB=1) more than t_{sc1} after regulator for internal blocks become active (PWR_DOWN=1)

2. Power-off sequence

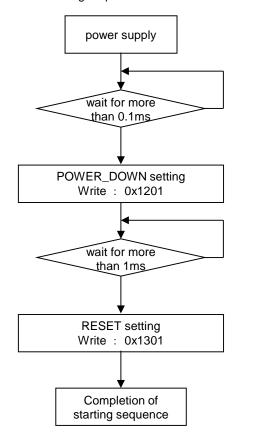


Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Wait time from power down command	tcps	0	-	-	μs	
Power supply OFF time	tpsl	1	-	-	ms	

Please send reset command (RSTB=0) to turn regulator for internal blocks off (PWR_DOWN=0) tcps before the VDD power-off.

Please keep VDD Low (VDD<0.4V) more than t_{PSL} before VDD power-on

3. Starting sequence

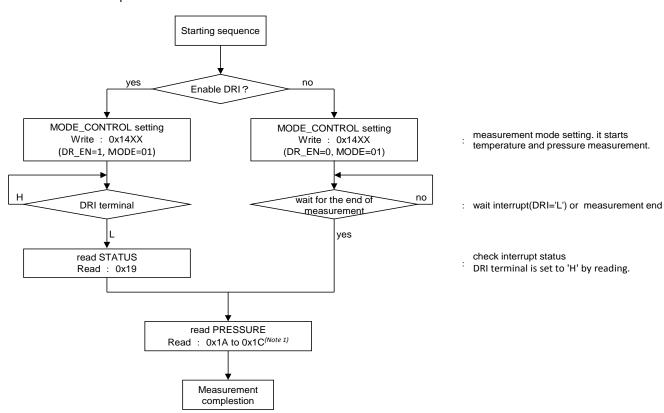


: release Power down

: release Reset mode

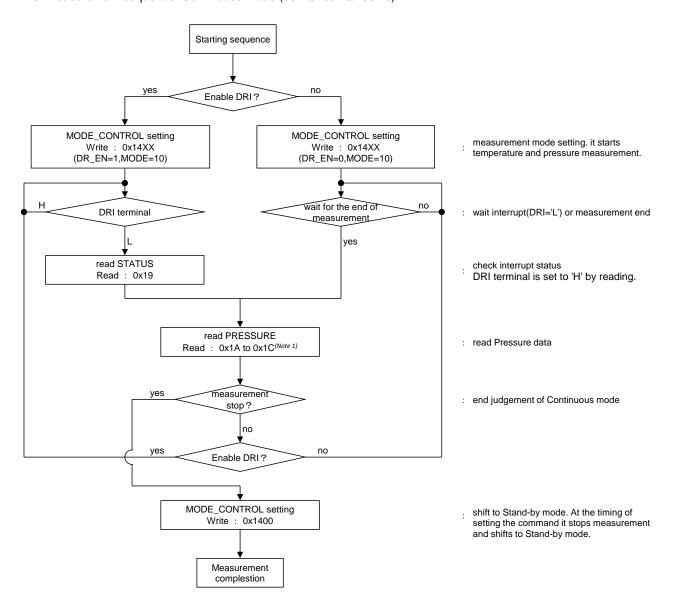
: Completion of operation preparation

4. Measurement sequence: One Shot Mode



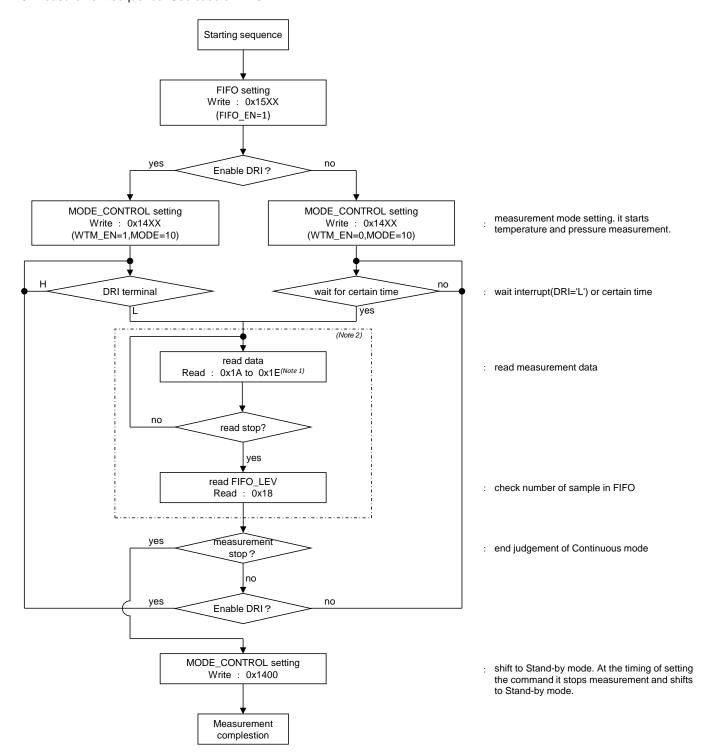
(Note 1) Data registers (0x1A, 0x1B, 0x1C) should be read by burst read.

5. Measurement sequence: Continuous Mode (50ms/100ms/200ms)



(Note 1) Data registers (0x1A, 0x1B, 0x1C) should be read by burst read.

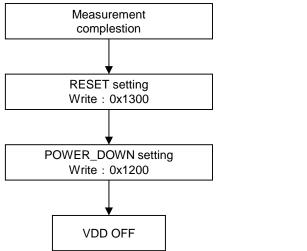
6. Measurement sequence: Use case of FIFO



(Note 1) Data registers (0x1A, 0x1B, 0x1C, 0x1D, 0x1E) should be read by burst read.

(Note 2) During a period form a start of FIFO reading (write to address 0x1A) to FIFO_LEV reading (write to address 0x18), do not communicate with this device. When communicating with this device during FIFO reading, read FIFO_LEV and finish FIFO read sequence before other communication. If don't read FIFO_LEV before other communication, there is a possibility to lose FIFO data.

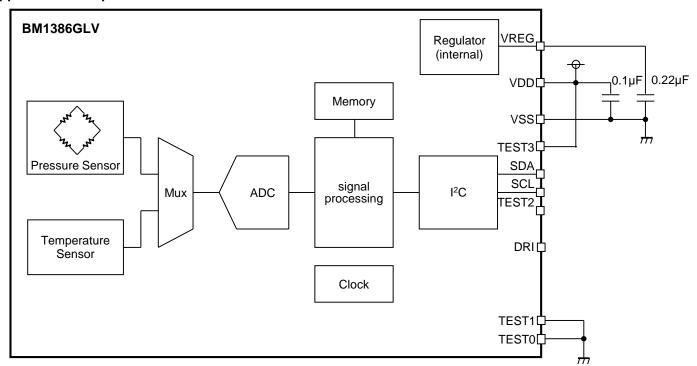
7. Ending sequence



: Reset

: power down

Application Example



I/O Equivalent Circuits

Equivalent Circuits Pin Name	Equivalent Circuit	Pin Name	Equivalent Circuit
SCL	VDD VDD	SDA	VDD VDD
TEST3	VDD VDD VDD	VREG	VDD
TEST2	VDD VDD	TEST0 TEST1	VDD VDD VDD
DRI			

Operational Notes

1. Reverse Connection of Power Supply

Connecting the power supply in reverse polarity can damage the IC. Take precautions against reverse polarity when connecting the power supply, such as mounting an external diode between the power supply and the IC's power supply pins.

2. Power Supply Lines

Design the PCB layout pattern to provide low impedance supply lines. Furthermore, connect a capacitor to ground at all power supply pins. Consider the effect of temperature and aging on the capacitance value when using electrolytic capacitors.

3. Ground Voltage

Ensure that no pins are at a voltage below that of the ground pin at any time, even during transient condition.

4. Ground Wiring Pattern

When using both small-signal and large-current ground traces, the two ground traces should be routed separately but connected to a single ground at the reference point of the application board to avoid fluctuations in the small-signal ground caused by large currents. Also ensure that the ground traces of external components do not cause variations on the ground voltage. The ground lines must be as short and thick as possible to reduce line impedance.

5. Recommended Operating Conditions

The function and operation of the IC are guaranteed within the range specified by the recommended operating conditions. The characteristic values are guaranteed only under the conditions of each item specified by the electrical characteristics.

6. Inrush Current

When power is first supplied to the IC, it is possible that the internal logic may be unstable and inrush current may flow instantaneously due to the internal powering sequence and delays, especially if the IC has more than one power supply. Therefore, give special consideration to power coupling capacitance, power wiring, width of ground wiring, and routing of connections.

7. Operation Under Strong Electromagnetic Field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

8. Testing on Application Boards

When testing the IC on an application board, connecting a capacitor directly to a low-impedance output pin may subject the IC to stress. Always discharge capacitors completely after each process or step. The IC's power supply should always be turned off completely before connecting or removing it from the test setup during the inspection process. To prevent damage from static discharge, ground the IC during assembly and use similar precautions during transport and storage.

9. Inter-pin Short and Mounting Errors

Ensure that the direction and position are correct when mounting the IC on the PCB. Incorrect mounting may result in damaging the IC. Avoid nearby pins being shorted to each other especially to ground, power supply and output pin. Inter-pin shorts could be due to many reasons such as metal particles, water droplets (in very humid environment) and unintentional solder bridge deposited in between pins during assembly to name a few.

10. Unused Input Pins

Input pins of an IC are often connected to the gate of a MOS transistor. The gate has extremely high impedance and extremely low capacitance. If left unconnected, the electric field from the outside can easily charge it. The small charge acquired in this way is enough to produce a significant effect on the conduction through the transistor and cause unexpected operation of the IC. So unless otherwise specified, unused input pins should be connected to the power supply or ground line.

Operational Notes - continued

11. Regarding the Input Pin of the IC

In the construction of this IC, P-N junctions are inevitably formed creating parasitic diodes or transistors. The operation of these parasitic elements can result in mutual interference among circuits, operational faults, or physical damage. Therefore, conditions which cause these parasitic elements to operate, such as applying a voltage to an input pin lower than the ground voltage should be avoided. Furthermore, do not apply a voltage to the input pins when no power supply voltage is applied to the IC. Even if the power supply voltage is applied, make sure that the input pins have voltages within the values specified in the electrical characteristics of this IC.

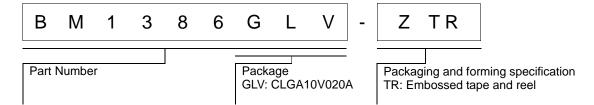
12. Ceramic Capacitor

When using a ceramic capacitor, determine the dielectric constant considering the change of capacitance with temperature and the decrease in nominal capacitance due to DC bias and others.

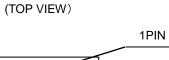
13. Disturbance light

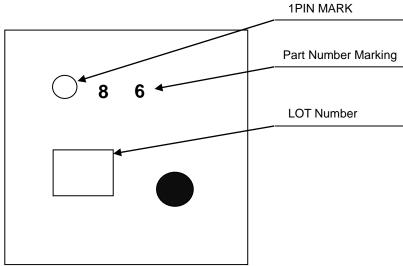
In a device where a portion of silicon is exposed to light such as in a WL-CSP, IC characteristics may be affected due to photoelectric effect. For this reason, it is recommended to come up with countermeasures that will prevent the chip from being exposed to light.

Ordering Information

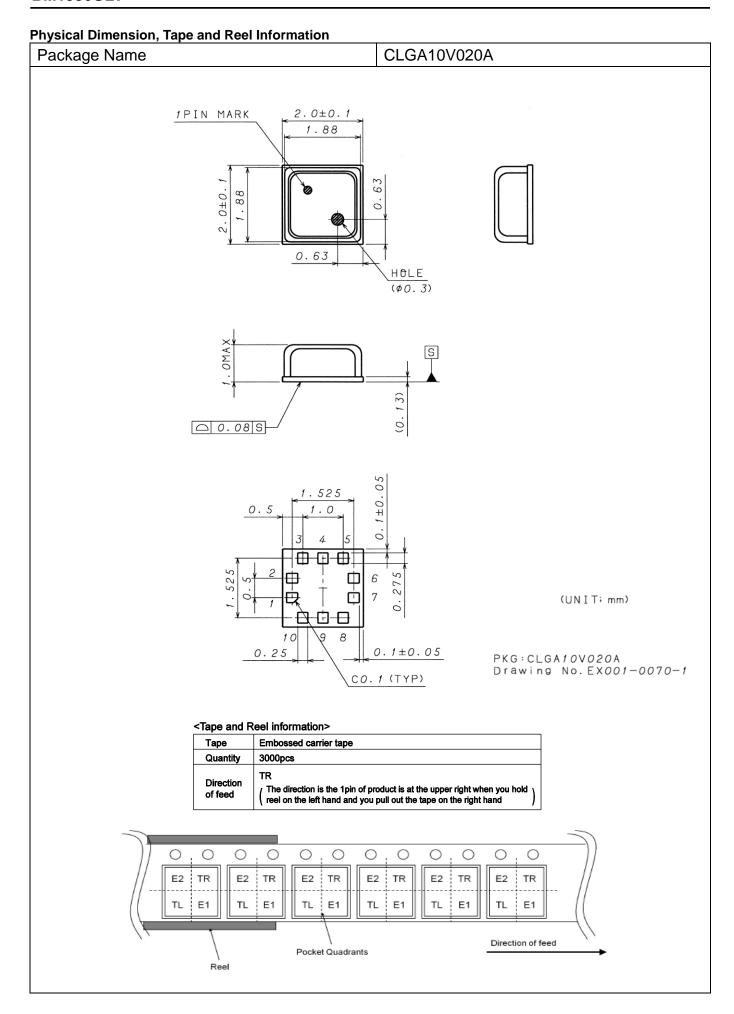


Marking Diagrams





CLGA10V020A



Revision History

Date	Revision	Changes
18.Aug.2017	001	New Release
14.Nov.2017	002	P7,10, 14,15 and 16 Correction of errors P19 Modify Measurement sequence: One Shot Mode, Correction of errors P20 Modify Measurement sequence: Continuous Mode, Correction of errors P21 Add Measurement sequence: Use case of FIFO, Correction of errors

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JÁPAN	USA	EU	CHINA
CLASSⅢ	CL ACCIII	CLASS II b	CL ACCIII
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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 - [h] Use of the Products in places subject to dew condensation
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- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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